

# Integrated Driver and MOSFET

## NCP302160R

The NCP302160R integrates a MOSFET driver, high-side MOSFET and low-side MOSFET into a single package.

The driver and MOSFETs have been optimized for high-current DC-DC buck power conversion applications. The NCP302160R integrated solution greatly reduces package parasitics and board space compared to a discrete component solution.

### Features

- Capable of Average Currents up to 60 A
- Capable of Peak Currents up to 80 A
- Capable of Switching at Frequencies up to 2 MHz
- Compatible with 3.3 V or 5 V PWM Input
- Responds Properly to 3-level PWM Inputs
- Internal Bootstrap Diode
- Undervoltage Lockout
- Supports Intel® Power State 4
- Thermal Warning output

### Applications

- Desktop and All-in-One Computers, V-Core and Non-V-Core DC-DC Converters
- High-Current DC-DC Point-of-Load Converters
- Small Form-Factor Voltage Regulator Modules

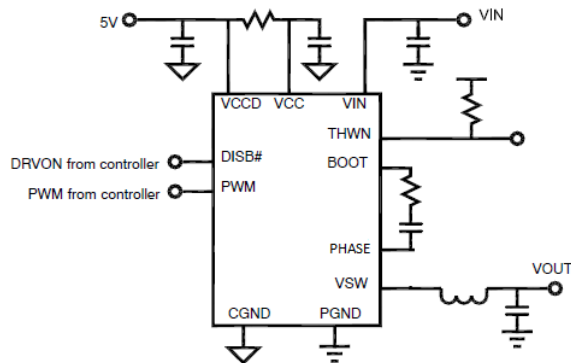
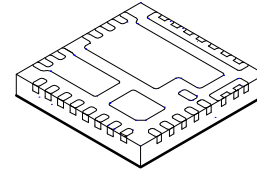
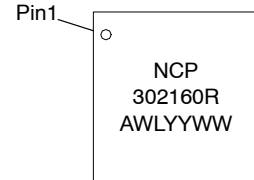


Figure 1. Application Schematic



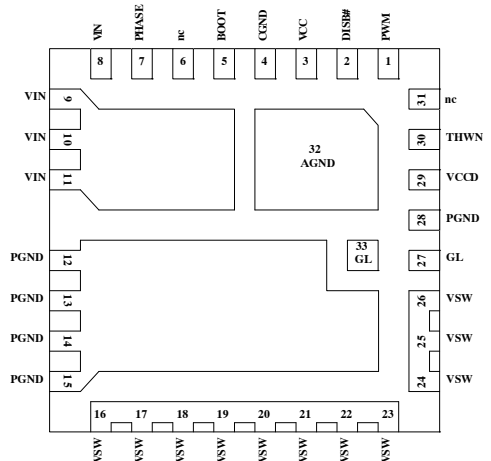
PQFN31 5X5, 0.5P  
CASE 483BR

### MARKING DIAGRAM



A = Assembly Location  
 WL = Wafer Lot  
 YY = Year  
 WW = Work Week

### PINOUT DIAGRAM



### ORDERING INFORMATION

| Device          | Package          | Shipping <sup>†</sup> |
|-----------------|------------------|-----------------------|
| NCP302160RMNTWG | PQFN31 (Pb-Free) | 3000 / Tape & Reel    |

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

# NCP302160R

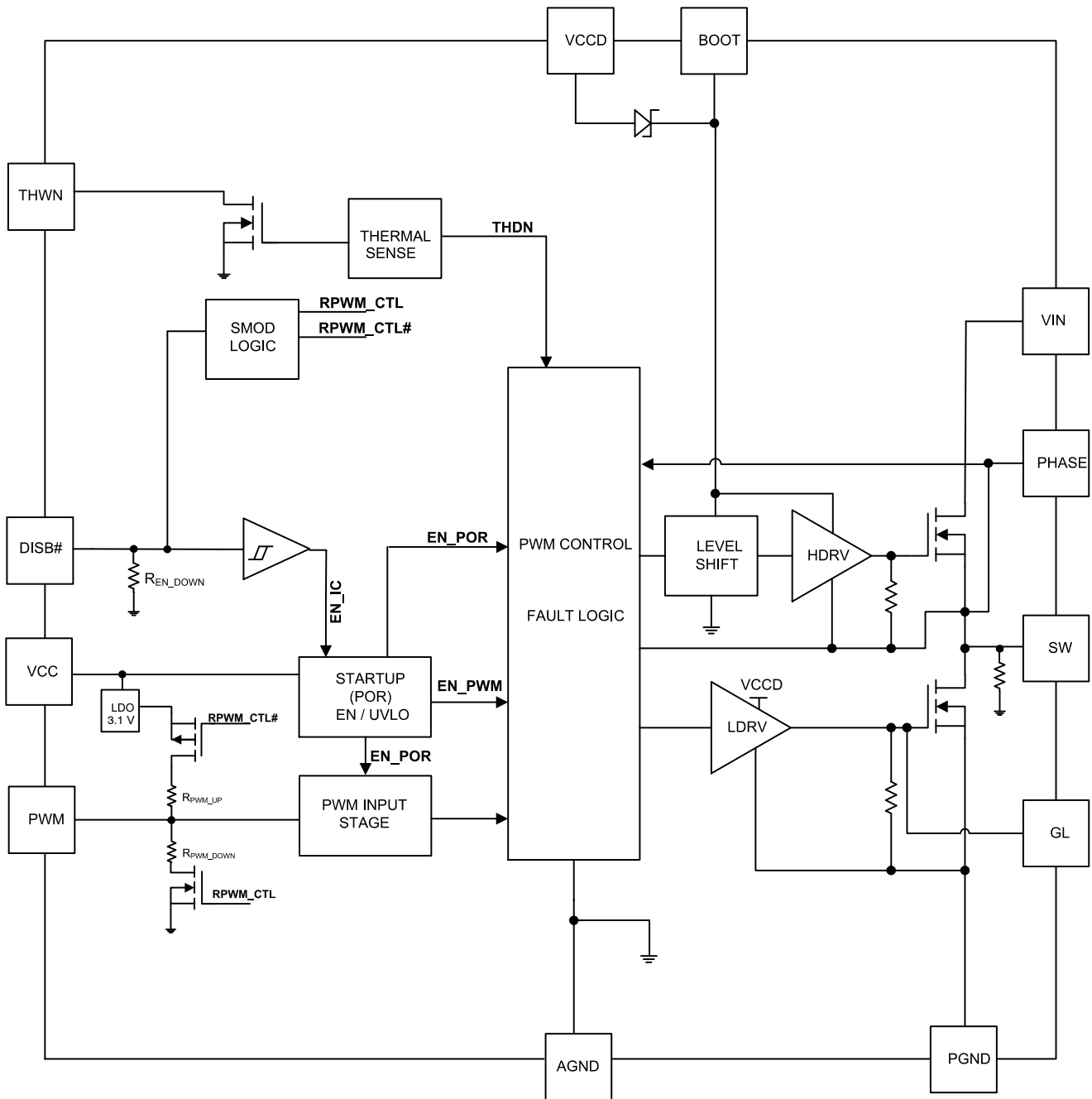


Figure 2. Block Diagram

# NCP302160R

**Table 1. PIN LIST AND DESCRIPTION**

| Pin No.   | Symbol     | Description                                                                                                                                                                                                                                                                    |
|-----------|------------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 1         | PWM        | PWM Control Input                                                                                                                                                                                                                                                              |
| 2         | DISB#      | Output disable pin.<br>High = Enabled with normal PWM operation without ZCD. Connects PWM to internal resistor divider placing a bias voltage on PWM pin.<br>Low = Driver is disabled and in a low power state.<br>There is an internal pull-down resistor to GND on this pin. |
| 3         | VCC        | Control Power Supply Input                                                                                                                                                                                                                                                     |
| 4, 32     | CGND, AGND | Signal Ground (pin 4 and pad 32 are internally connected)                                                                                                                                                                                                                      |
| 5         | BOOT       | Bootstrap Voltage                                                                                                                                                                                                                                                              |
| 6         | NC         | Open pin (not used)                                                                                                                                                                                                                                                            |
| 7         | PHASE      | Bootstrap Capacitor Return                                                                                                                                                                                                                                                     |
| 8–11      | VIN        | Conversion Supply Power Input                                                                                                                                                                                                                                                  |
| 12–15, 28 | PGND       | Power Ground                                                                                                                                                                                                                                                                   |
| 16–26     | VSW        | Switch Node Output                                                                                                                                                                                                                                                             |
| 27, 33    | GL         | Low Side FET Gate Access (pin 27 and pad 33 are internally connected)                                                                                                                                                                                                          |
| 29        | VCCD       | Driver Power Supply Input                                                                                                                                                                                                                                                      |
| 30        | THWN       | Thermal warning indicator. This is an open-drain output. When the temperature at the driver die reaches $T_{THWN}$ , this pin is pulled low.                                                                                                                                   |
| 31        | NC         | Open pin (not used)                                                                                                                                                                                                                                                            |

# NCP302160R

**Table 2. ABSOLUTE MAXIMUM RATINGS** (Electrical Information – all signals referenced to PGND unless noted otherwise)

| Pin Name / Parameter    | Min  | Max             | Unit |
|-------------------------|------|-----------------|------|
| VCC, VCCD               | –0.3 | 6.5             | V    |
| VIN                     | –0.3 | 30              | V    |
| VIN to PHASE (DC)       | –0.3 | 30              | V    |
| VIN to PHASE (< 5 ns)   | –3   | 35              | V    |
| BOOT (DC)               | –0.3 | 30              | V    |
| BOOT (< 5 ns)           | –9   | 35              | V    |
| BOOT to PHASE (DC)      | –0.3 | 6.5             | V    |
| BOOT to PHASE (< 20 ns) | –0.3 | 9.0             | V    |
| VSW, PHASE (DC)         | –0.3 | 30              | V    |
| VSW, PHASE (< 5 ns)     | –15  | 36              | V    |
| All Other Pins          | –0.3 | $V_{VCC} + 0.3$ | V    |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

**Table 3. THERMAL INFORMATION**

| Rating                                               | Symbol           | Value       | Unit |
|------------------------------------------------------|------------------|-------------|------|
| Thermal Resistance (under On Semi SPS Thermal Board) | $\theta_{JA}$    | 12.4        | °C/W |
|                                                      | $\theta_{J-PCB}$ | 1.8         | °C/W |
| Operating Junction Temperature Range (Note 1)        | $T_J$            | –40 to +150 | °C   |
| Operating Ambient Temperature Range                  | $T_A$            | –40 to +125 | °C   |
| Maximum Storage Temperature Range                    | $T_{STG}$        | –55 to +150 | °C   |
| Moisture Sensitivity Level                           | MSL              | 1           |      |

1. The maximum package power dissipation must be observed.
2. JESD 51–5 (1S2P Direct–Attach Method) with 0 LFM
3. JESD 51–7 (1S2P Direct–Attach Method) with 0 LFM

**Table 4. RECOMMENDED OPERATING CONDITIONS**

| Parameter             | Pin Name  | Conditions | Min  | Typ | Max | Unit |
|-----------------------|-----------|------------|------|-----|-----|------|
| Supply Voltage Range  | VCC, VCCD |            | 4.5  | 5.0 | 5.5 | V    |
| Conversion Voltage    | VIN       |            | 4.5  | –   | 20  | V    |
| Peak Negative Current | SW        |            | –100 |     |     | A    |
| Junction Temperature  |           |            | –40  |     | 125 | °C   |

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

# NCP302160R

**Table 5. ELECTRICAL CHARACTERISTICS**

( $V_{VCC} = V_{VCCD} = 5.0\text{ V}$ ,  $V_{VIN} = 12\text{ V}$ ,  $V_{DISB\#} = 2.0\text{ V}$ ,  $C_{VCCD} = C_{VCC} = 0.1\text{ }\mu\text{F}$  unless specified otherwise) Min/Max values are valid for the temperature range  $-40^{\circ}\text{C} \leq T_J \leq 125^{\circ}\text{C}$  unless noted otherwise, and are guaranteed by test, design or statistical correlation.)

| Parameter | Symbol | Conditions | Min. | Typ. | Max. | Unit |
|-----------|--------|------------|------|------|------|------|
|-----------|--------|------------|------|------|------|------|

## VCC SUPPLY CURRENT

|                      |            |                            |      |     |     |               |
|----------------------|------------|----------------------------|------|-----|-----|---------------|
| Operating            |            | DISB# = 5 V, PWM = 400 kHz | –    | 1   | 2   | mA            |
| No switching         |            | DISB# = 5 V, PWM = 0 V     | –    | –   | 2   | mA            |
| Disabled             |            | DISB# = 0 V                | –    | 0.4 | 1   | $\mu\text{A}$ |
| UVLO Start Threshold | $V_{UVLO}$ | VCC rising                 | 3.65 | –   | 4.1 | V             |
| UVLO Hysteresis      |            |                            | 400  | 500 | –   | mV            |

## VCCD SUPPLY CURRENT

|                       |  |                                                      |   |     |     |               |
|-----------------------|--|------------------------------------------------------|---|-----|-----|---------------|
| Enabled, No switching |  | DISB# = 5 V, PWM = 0 V,<br>$V_{PHASED} = 0\text{ V}$ | – | 175 | 300 | $\mu\text{A}$ |
| Disabled              |  | DISB# = 0 V                                          | – | 0.4 | 1   | $\mu\text{A}$ |
| Operating             |  | DISB# = 5 V, PWM = 400 kHz                           | – | –   | 30  | mA            |

## DISB# INPUT

|                    |             |                                                                     |     |     |     |               |
|--------------------|-------------|---------------------------------------------------------------------|-----|-----|-----|---------------|
| Input Resistance   |             | To Ground                                                           | –   | 467 | –   | k $\Omega$    |
| Upper Threshold    | $V_{UPPER}$ |                                                                     | –   | –   | 2.0 | V             |
| Lower Threshold    | $V_{LOWER}$ |                                                                     | 0.8 | –   | –   | V             |
| Hysteresis         |             | $V_{UPPER} - V_{LOWER}$                                             | 200 | –   | –   | mV            |
| Enable Delay Time  |             | Time from DISB# transitioning HI to when VSW responds to PWM.       | –   | 28  | 52  | $\mu\text{s}$ |
| Disable Delay Time |             | Time from DISB# transitioning LOW to when both output FETs are off. | –   | 21  | 50  | ns            |

## PWM INPUT

|                                                     |                    |                                         |      |      |     |            |
|-----------------------------------------------------|--------------------|-----------------------------------------|------|------|-----|------------|
| Input Voltage High                                  | $V_{PWM\_HI}$      |                                         | 2.95 | –    | –   | V          |
| Input Mid-state Voltage                             | $V_{PWM\_MID}$     |                                         | 1.25 | –    | 2.3 | V          |
| Input Low Voltage                                   | $V_{PWM\_LO}$      |                                         | –    | –    | 0.7 | V          |
| Input Resistance                                    | $R_{PWM\_BIAS}$    | DISB# = 5 V                             | 9.2  | 14.6 | 20  | k $\Omega$ |
| PWM Input Bias Voltage                              | $V_{PWM\_BIAS}$    | DISB# = 5 V                             | 1.2  | 1.7  | 2.3 | V          |
| Non-overlap Delay, Leading Edge                     | $T_{NOL\_L}$       | GL Falling = 1 V to GH-VSW Rising = 1 V | –    | 13   | –   | ns         |
| Non-overlap Delay, Trailing Edge                    | $T_{NOL\_T}$       | GH-VSW Falling = 1 V to GL Rising = 1 V | –    | 12   | –   | ns         |
| PWM Propagation Delay, Rising                       | $T_{PWM\_PD\_R}$   | PWM = High to GL = 90%                  | –    | 13   | 35  | ns         |
| PWM Propagation Delay, Falling                      | $T_{PWM\_PD\_F}$   | PWM = Low to SW = 90%                   | –    | 50   | 65  | ns         |
| Exiting PWM Mid-state Propagation Delay, Mid-to-Low | $T_{PWM\_EXIT\_L}$ | PWM = Mid-to-Low to GL = 10%            | –    | 14   | 25  | ns         |

## THERMAL WARNING

|                             |                 |                           |   |     |   |                    |
|-----------------------------|-----------------|---------------------------|---|-----|---|--------------------|
| Thermal Warning Temperature | $T_{THWN}$      | Temperature at Driver Die | – | 150 | – | $^{\circ}\text{C}$ |
| Thermal Warning Hysteresis  | $T_{THWN\_HYS}$ |                           | – | 15  | – | $^{\circ}\text{C}$ |
| THWM Open Drain Current     | $I_{THWN}$      |                           | – | –   | 5 | mA                 |

## BOOT STRAP DIODE

|                 |  |                               |   |     |   |    |
|-----------------|--|-------------------------------|---|-----|---|----|
| Forward Voltage |  | Forward Bias Current = 2.0 mA | – | 380 | – | mV |
|-----------------|--|-------------------------------|---|-----|---|----|

## HIGH-SIDE DRIVER

|                            |                  |                         |   |     |   |          |
|----------------------------|------------------|-------------------------|---|-----|---|----------|
| Output Impedance, Sourcing | $R_{SOURCE\_GH}$ | Source Current = 100 mA | – | 0.9 | – | $\Omega$ |
|----------------------------|------------------|-------------------------|---|-----|---|----------|

# NCP302160R

**Table 5. ELECTRICAL CHARACTERISTICS**

( $V_{VCC} = V_{VCCD} = 5.0\text{ V}$ ,  $V_{VIN} = 12\text{ V}$ ,  $V_{DISB\#} = 2.0\text{ V}$ ,  $C_{VCCD} = C_{VCC} = 0.1\text{ }\mu\text{F}$  unless specified otherwise) Min/Max values are valid for the temperature range  $-40^{\circ}\text{C} \leq T_J \leq 125^{\circ}\text{C}$  unless noted otherwise, and are guaranteed by test, design or statistical correlation.)

| Parameter | Symbol | Conditions | Min. | Typ. | Max. | Unit |
|-----------|--------|------------|------|------|------|------|
|-----------|--------|------------|------|------|------|------|

## HIGH-SIDE DRIVER

|                           |                |                       |   |     |   |          |
|---------------------------|----------------|-----------------------|---|-----|---|----------|
| Output Impedance, Sinking | $R_{SINK\_GH}$ | Sink Current = 100 mA | – | 0.7 | – | $\Omega$ |
|---------------------------|----------------|-----------------------|---|-----|---|----------|

## LOW-SIDE DRIVER

|                            |                  |                         |   |     |   |          |
|----------------------------|------------------|-------------------------|---|-----|---|----------|
| Output Impedance, Sourcing | $R_{SOURCE\_GL}$ | Source Current = 100 mA | – | 0.9 | – | $\Omega$ |
| Output Impedance, Sinking  | $R_{SINK\_GL}$   | Sink Current = 100 mA   | – | 0.4 | – | $\Omega$ |
| GL Rise Time               | $T_{R\_GL}$      | GL = 10% to 90%         | – | 12  | – | ns       |
| GL Fall Time               | $T_{F\_GL}$      | GL = 90% to 10%         | – | 6   | – | ns       |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

**Table 6. LOGIC TABLE**

| DISB# | PWM | GH (not a pin) | GL |
|-------|-----|----------------|----|
| L     | X   | L              | L  |
| H     | H   | H              | L  |
| H     | L   | L              | H  |
| H     | MID | L              | L  |

## TYPICAL PERFORMANCE CHARACTERISTICS

(Test Conditions:  $V_{IN}=12\text{ V}$ ,  $V_{CC}=PV_{CC}=5\text{ V}$ ,  $V_{OUT}=1\text{ V}$ ,  $L_{OUT}=250\text{ nH}$ ,  $T_A=25^\circ\text{C}$  and natural convection cooling, unless otherwise noted)

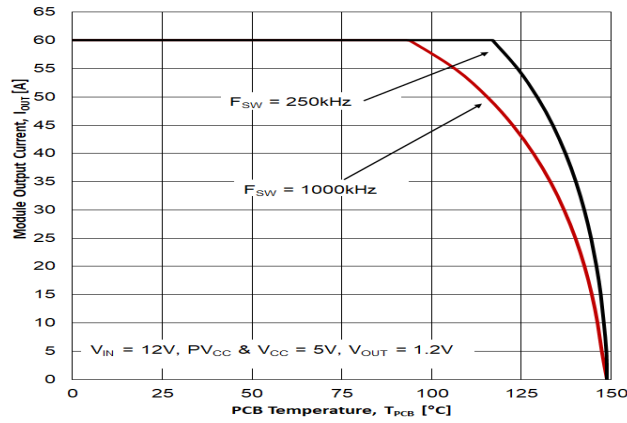


Figure 3. Safe Operating Area with 12  $V_{IN}$

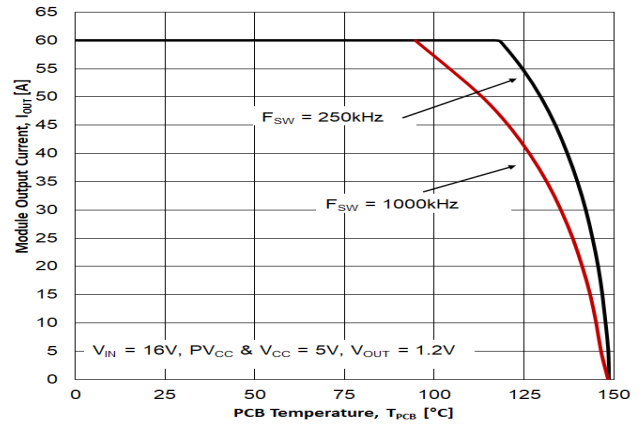


Figure 4. Safe Operating Area with 16  $V_{IN}$

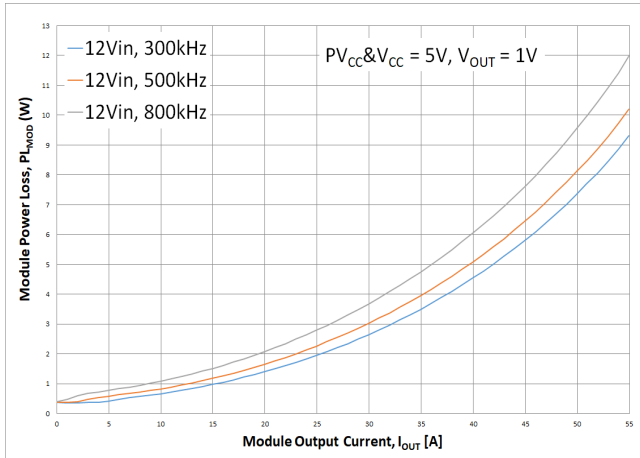


Figure 5. Power Loss vs. Output Current with 12  $V_{IN}$

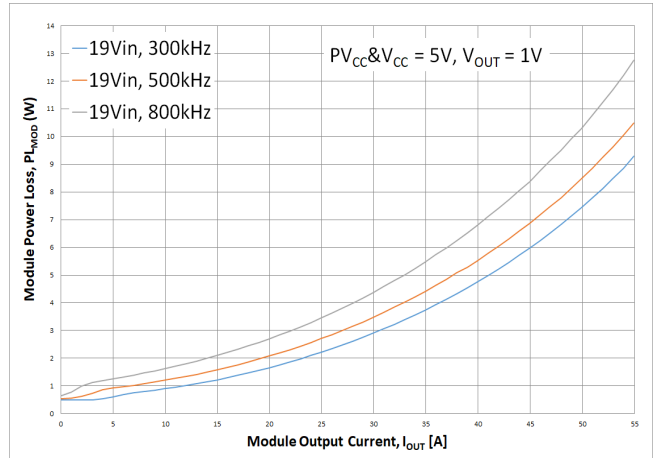


Figure 6. Power Loss vs. Output Current with 19  $V_{IN}$

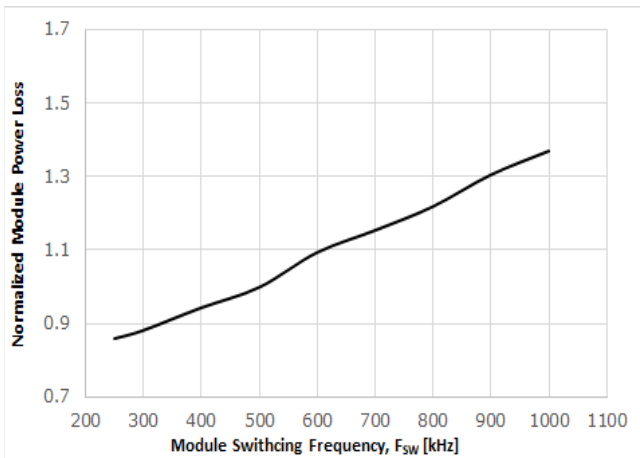


Figure 7. Power Loss vs. Switching Frequency

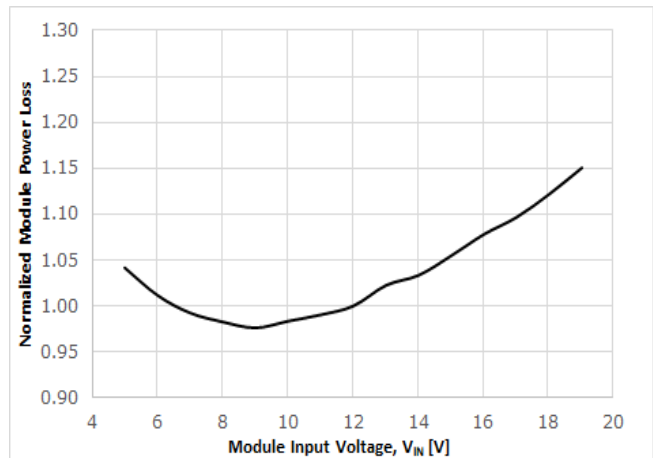


Figure 8. Power Loss vs. Input Voltage

## TYPICAL PERFORMANCE CHARACTERISTICS

(Test Conditions:  $V_{IN}=12\text{ V}$ ,  $V_{CC}=PV_{CC}=5\text{ V}$ ,  $V_{OUT}=1\text{ V}$ ,  $L_{OUT}=250\text{ nH}$ ,  $T_A=25^\circ\text{C}$  and natural convection cooling, unless otherwise noted)

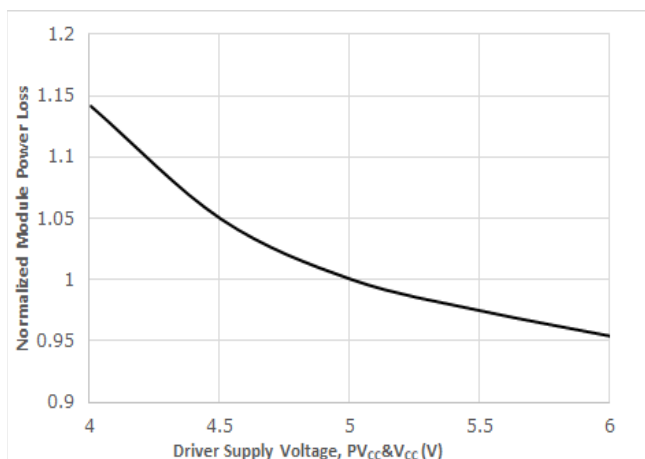


Figure 9. Power Loss vs. Driver Supply Voltage

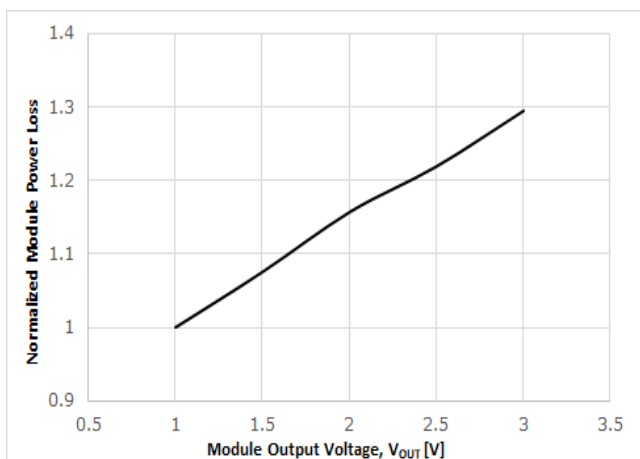


Figure 10. Power Loss vs. Output Voltage

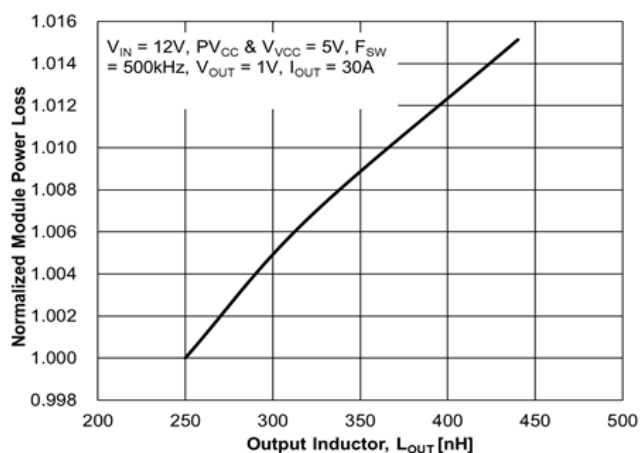


Figure 11. Power Loss vs. Output Inductor

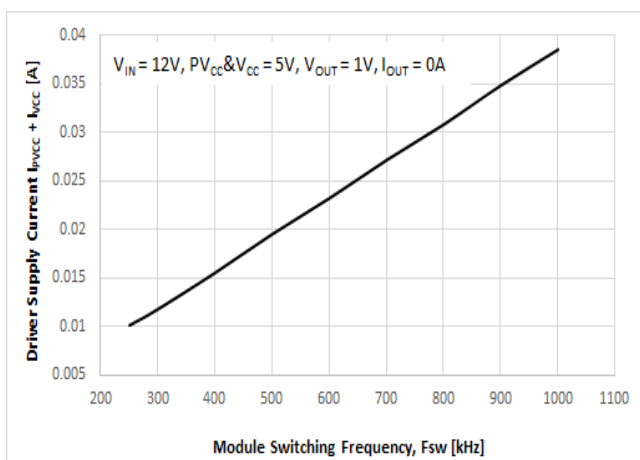


Figure 12. Driver Supply Current vs. Switching Frequency

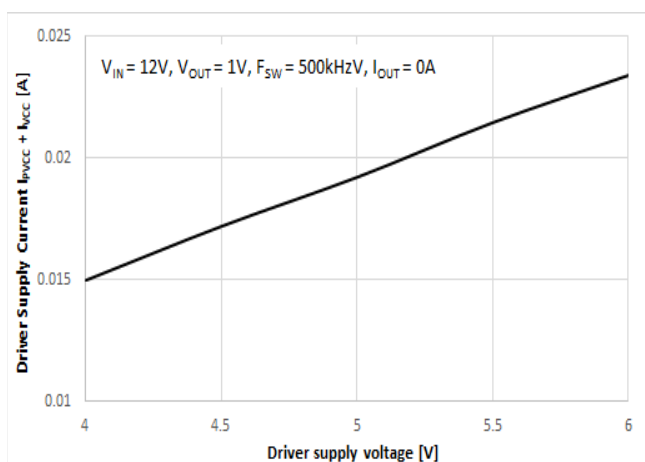


Figure 13. Driver Supply Current vs. Driver Supply Voltage

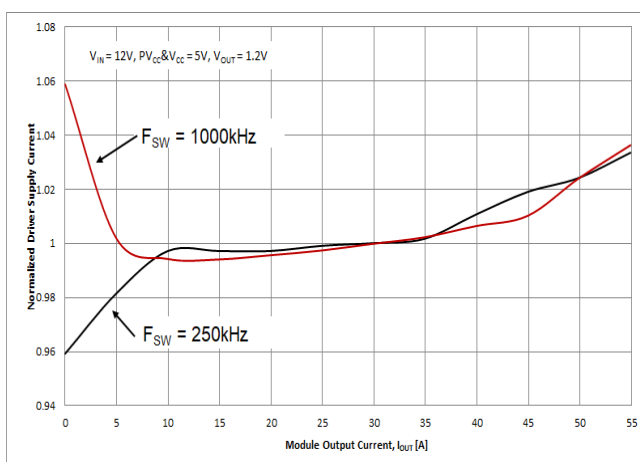


Figure 14. Driver Supply Current vs. Output Current

# TYPICAL PERFORMANCE CHARACTERISTICS

(Test Conditions:  $V_{IN}=12\text{ V}$ ,  $V_{CC}=PV_{CC}=5\text{ V}$ ,  $V_{OUT}=1\text{ V}$ ,  $L_{OUT}=250\text{ nH}$ ,  $T_A=25^\circ\text{C}$  and natural convection cooling, unless otherwise noted)

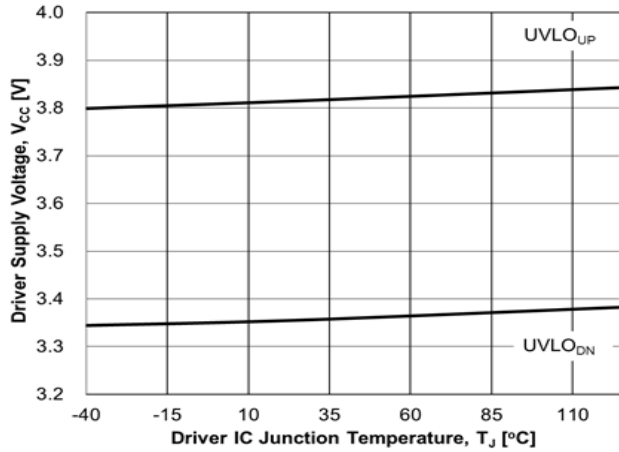


Figure 15. UVLO Threshold vs. Temperature

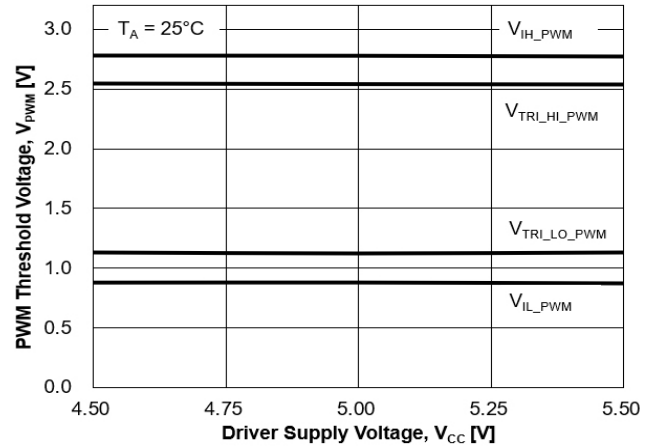


Figure 16. PWM Threshold vs. Driver Supply Voltage

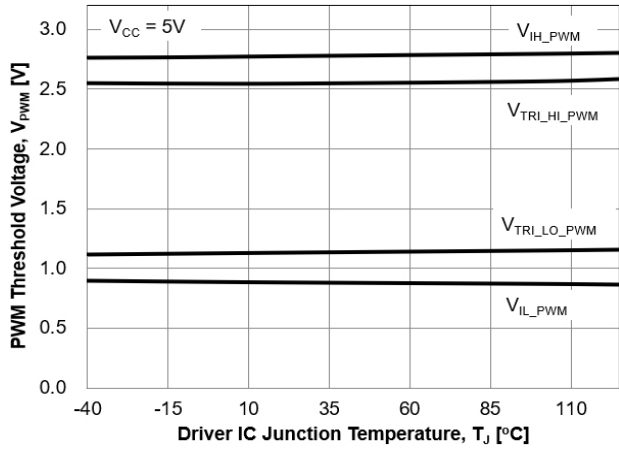


Figure 17. PWM Threshold vs. Temperature

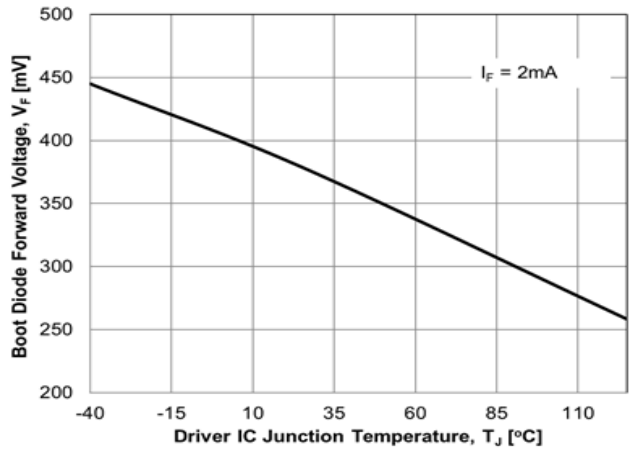


Figure 18. Body Diode Forward Voltage vs. Temperature

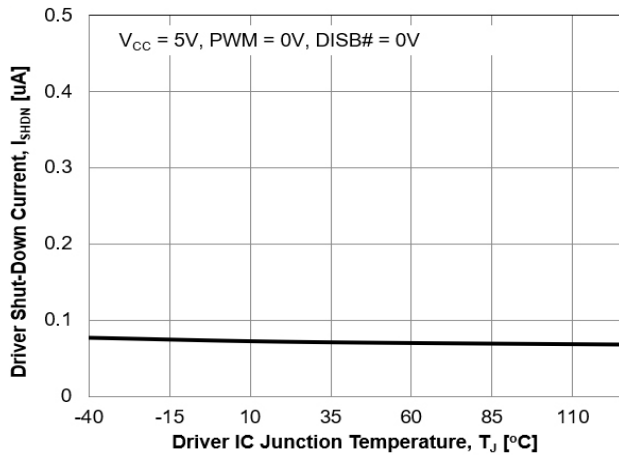


Figure 19. Driver Shutdown vs. Temperature

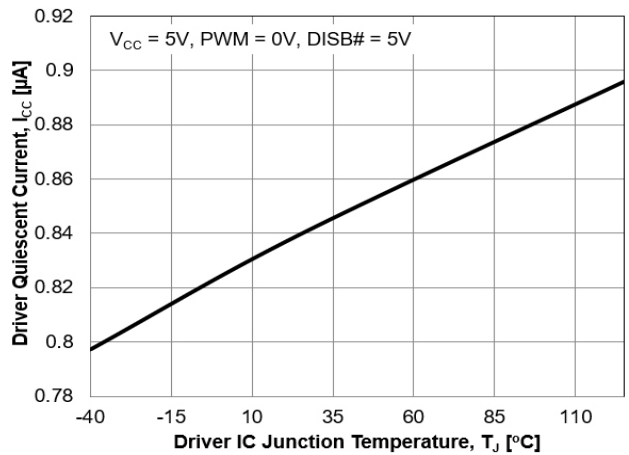


Figure 20. Driver Quiescent Current vs. Temperature

## Theory of Operation

The NCP302160R is an integrated driver and MOSFET module designed for use in a synchronous buck converter topology. The NCP302160R supports PWM Tristate control. A PWM input signal is required to control the drive signals to the high-side and low-side integrated MOSFETs.

### Low-Side Driver

The low-side driver drives an internal, ground-referenced low- $R_{DS(on)}$  N-Channel MOSFET. The voltage supply for the low-side driver is internally connected to the VCCD and PGND pins.

### High-Side Driver

The high-side driver drives an internal, floating low- $R_{DS(on)}$  N-channel MOSFET. The gate voltage for the high side driver is developed by a bootstrap circuit referenced to Switch Node (VSW and PHASE) pins.

The bootstrap circuit is comprised of the integrated diode and an external bootstrap capacitor and resistor. When the NCP302160R is starting up, the VSW pin is at ground, allowing the bootstrap capacitor to charge up to VCCD through the bootstrap diode (See Figure 1). When the PWM input is driven high, the high-side driver turns on the high-side MOSFET using the stored charge of the bootstrap capacitor. As the high-side MOSFET turns on, the voltage at the VSW and PHASE pins rises. When the high-side MOSFET is fully turned on, the switch node settles to VIN and the BST pin settles to VIN + VCCD (excluding parasitic ringing).

### Bootstrap Circuit

The bootstrap circuit relies on an external charge storage capacitor ( $C_{BST}$ ) and an integrated diode to provide current to the HS Driver. A multi-layer ceramic capacitor (MLCC) with a value greater than 100 nF should be used as the bootstrap capacitor. An optional 1 to 4  $\Omega$  resistor in series with the bootstrap capacitor decreases the VSW overshoot. The boot resistor is strongly recommended when VIN is higher than 15 V.

### Power Supply Decoupling

The NCP302160R sources relatively large currents into the MOSFET gates. In order to maintain a constant and stable supply voltage (VCCD) a low-ESR capacitor should be placed near the power and ground pins. A multi-layer ceramic capacitor (MLCC) between 1  $\mu$ F and 4.7  $\mu$ F is typically used.

A separate supply pin (VCC) is used to power the analog and digital circuits within the driver. A 1  $\mu$ F ceramic capacitor should be placed on this pin in close proximity to the NCP302160R. It is good practice to separate the VCC and VCCD decoupling capacitors with a resistor (10  $\Omega$  typical) to avoid coupling driver noise to the analog and digital circuits that control the driver function (See Figure 1).

## Safety Timer and Overlap Protection Circuit

It is important to avoid cross-conduction of the two MOSFETs which could result in a decrease in the power conversion efficiency or damage to the device.

The NCP302160R prevents cross-conduction by monitoring the status of the MOSFETs and applying the appropriate amount of non-overlap (NOL) time (the time between the turn-off of one MOSFET and the turn-on of the other MOSFET). When the PWM input pin is driven high, the gate of the low-side MOSFET (LSGATE) goes low after a propagation delay (tpdLGL). The time it takes for the low-side MOSFET to turn off is dependent on the total charge on the low-side MOSFET gate.

The NCP302160R monitors the gate voltage of both MOSFETs and the switch node voltage to determine the conduction status of the MOSFETs. Once the low-side MOSFET is turned off an internal timer delays (tpdhGH) the turn-on of the high-side MOSFET. When the PWM input pin goes low, the gate of the high-side MOSFET (HSGATE) goes low after the propagation delay (tpdIGH). The time to turn off the high-side MOSFET (tfGH) is dependent on the total gate charge of the high-side MOSFET. A timer is triggered once the high-side MOSFET stops conducting, to delay (tpdhGL) the turn-on of the low-side MOSFET.

### PWM Input

The PWM Input pin is a tri-state input used to control the HS MOSFET ON/OFF state. It also determines the state of the LS MOSFET. See Table 6 for logic operation.

When DISB# is high the PWM pin undriven default voltage is set to Mid-State with internal divider resistances.

### Disable Input (DISB#)

The DISB# pin is used to disable the GH to the High-Side FET to prevent power transfer when set to low. The pin has a pull-down resistance to force a disabled state when it is left unconnected. When DISB# is set to high it enables normal PWM operation without ZCD. DISB# can be driven from the output of a logic device or set high with a pull-up resistance to VCC.

### VCC Undervoltage Lockout

The VCC pin is monitored by an Undervoltage Lockout Circuit (UVLO). VCC voltage above the rising threshold enables the NCP302160R.

Table 7. UVLO/DISB# LOGIC TABLE

| UVLO | DISE# | Driver State           |
|------|-------|------------------------|
| L    | X     | Disabled (GH = GL = 0) |
| H    | L     | Disabled (GH = GL = 0) |
| H    | H     | Enabled (See Table 1)  |
| H    | Open  | Disabled (GH = GL = 0) |

### Thermal Warning

The THWN pin is an open drain output. When the temperature of the driver exceeds  $T_{THWN}$ , the THWN pin is

pulled low indicating a thermal warning. At this point, the part continues to function normally. When the temperature drops  $T_{THWN\_HYS}$  below  $T_{THWN}$ , the THWN pin goes high.

### FOR USE WITH CONTROLLERS WITH 3-STATE PWM CONTROLLERS DETECTION CAPABILITY:

Table 8. LOGIC TABLE – 3-STATE PWM CONTROLLERS WITH ZCD

| PWM | DISB# | GH (not a pin) | GL  |
|-----|-------|----------------|-----|
| H   | H     | ON             | OFF |
| M   | H     | OFF            | OFF |
| L   | H     | OFF            | ON  |

This section describes operation with controllers that are capable of 3 PWM output levels and have zero current detection during discontinuous conduction mode (DCM).

To operate the buck converter in continuous conduction mode (CCM), PWM needs to switch between the logic high and low states. During DCM, the controller is responsible

for detecting when zero current has occurred, and then notifying the NCP302160R to turn off the LS FET. When the controller detects zero current, it needs to set PWM to mid-state, which causes the NCP302160R to pull both GH and GL to their off states without delay.

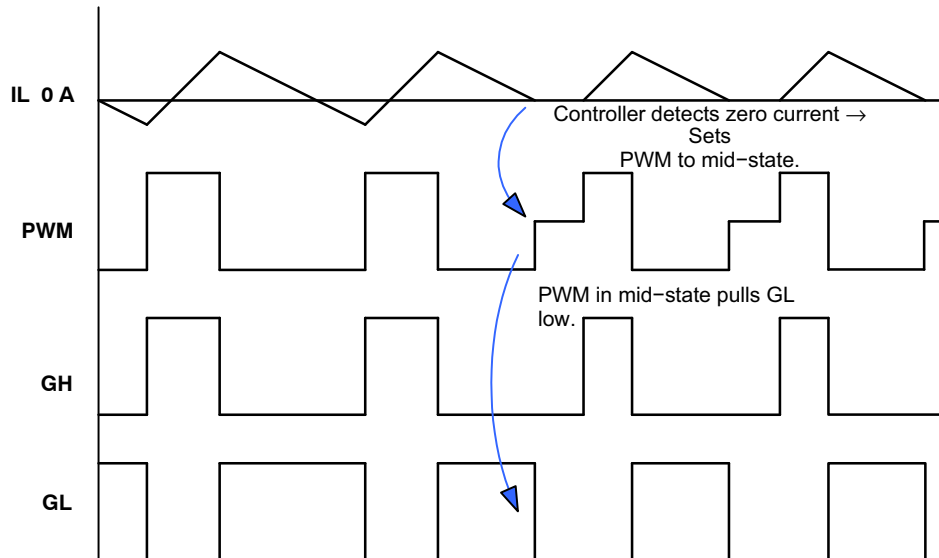


Figure 21. Timing Diagram – 3-state PWM Controller, with ZCD

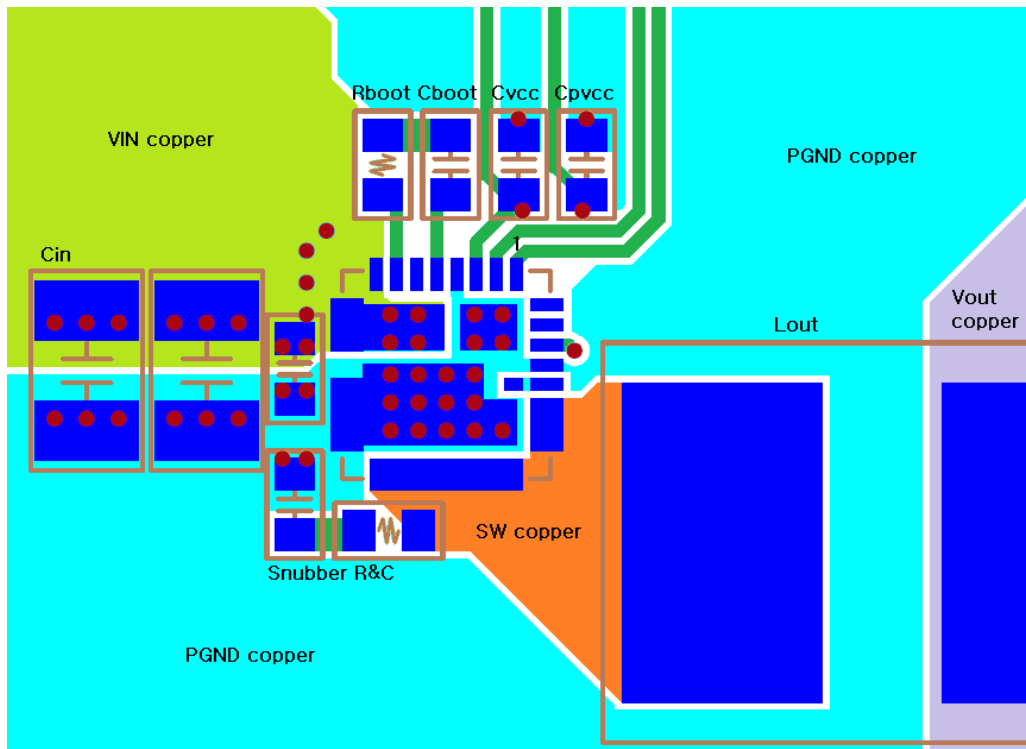


Figure 22. Top Copper Layer

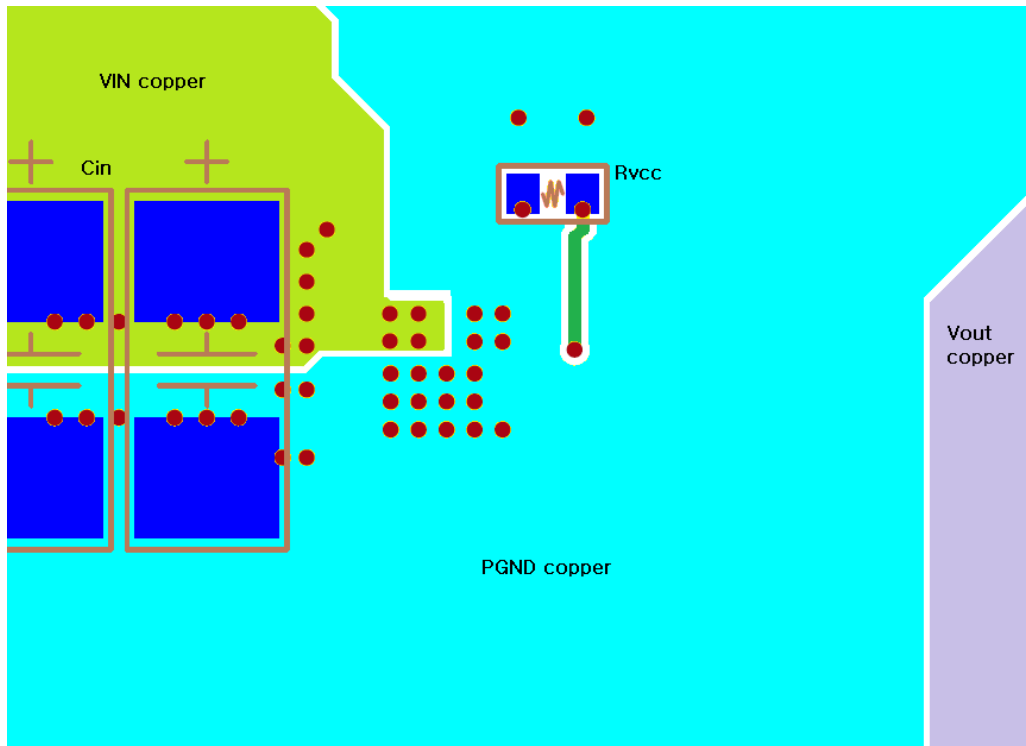


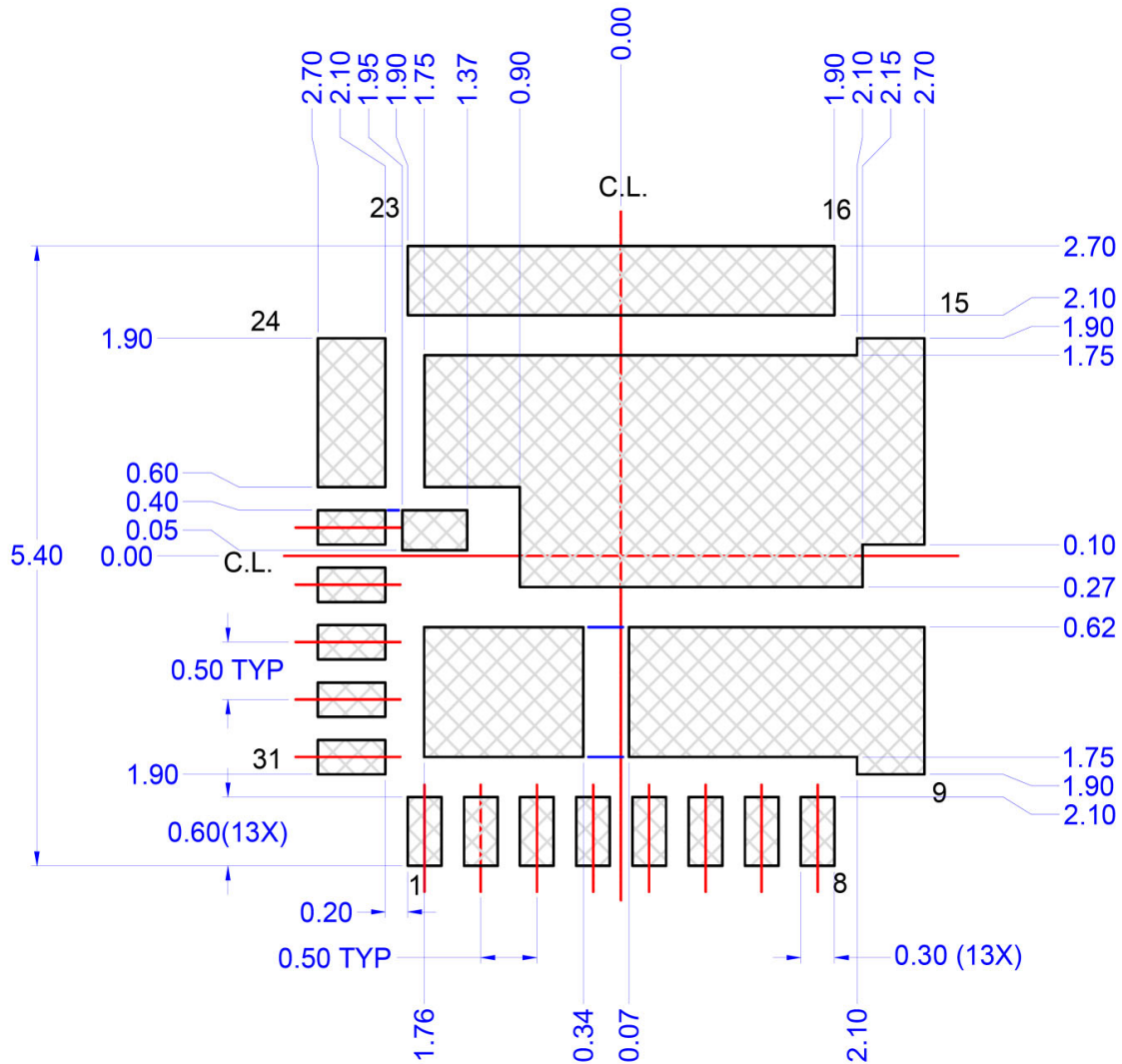
Figure 23. Bottom Copper Layer

### RECOMMENDED PCB FOOTPRINT



# NCP302160R

## RECOMMENDED PCB FOOTPRINT (Option 2)

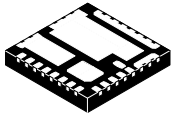


## LAND PATTERN RECOMMENDATION

### REVISION HISTORY

| Revision | Description of Changes   | Date      |
|----------|--------------------------|-----------|
| 3        | Add a new row to table 4 | 5/30/2025 |

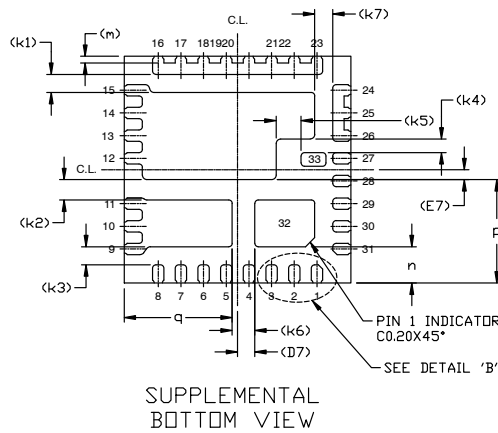
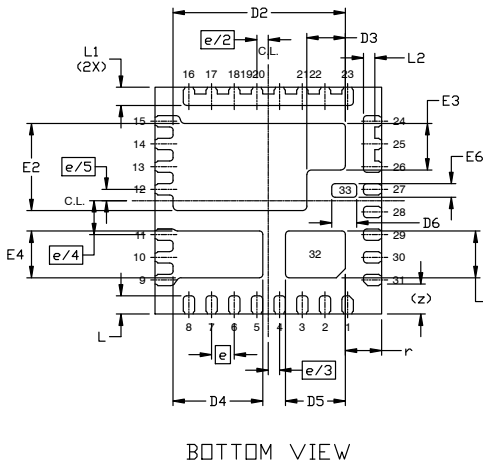
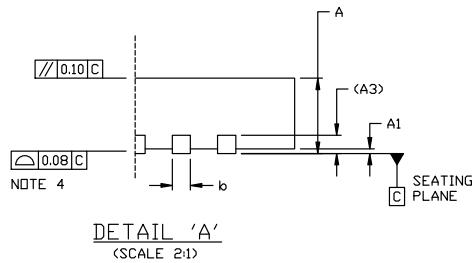
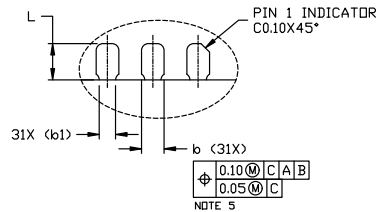
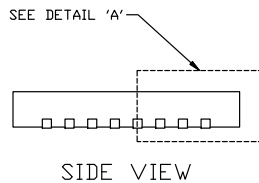
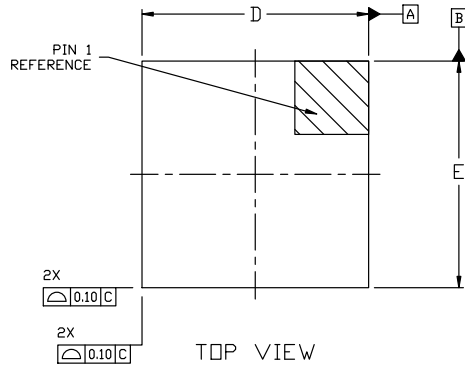
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SCALE 2.5:1

PQFN31 5X5, 0.5P  
CASE 483BR  
ISSUE D

DATE 13 FEB 2023



NOTES:

1. DOES NOT FULLY CONFORM TO JEDEC REGISTRATION MO-220, DATES MAY/2005.
2. DIMENSIONING AND TOLERANCING PER ASME Y14.5, 2009.
3. CONTROLLING DIMENSION: MILLIMETERS
4. DIMENSIONS DO NOT INCLUDE BURRS AND SMEAR OR MOLD FLASH.
5. MOLD FLASH OR BURRS AND SMEAR DO NOT EXCEED 0.10MM.
6. DIMENSION b AND B1 APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.30 FROM THE TERMINAL TIP.

| DIM | MILLIMETERS |      |      |
|-----|-------------|------|------|
|     | MIN.        | NOM. | MAX. |
| A   | 0.70        | 0.75 | 0.80 |
| A1  | 0.00        | -    | 0.05 |
| A3  | 0.15        | 0.20 | 0.25 |
| b   | 0.20        | 0.25 | 0.30 |
| b1  | 0.13        | 0.18 | 0.30 |
| D   | 4.90        | 5.00 | 5.10 |
| D2  | 3.70        | 3.80 | 3.90 |
| D3  | 0.75        | 0.85 | 0.95 |
| D4  | 1.88        | 1.98 | 2.08 |
| D5  | 1.22        | 1.32 | 1.42 |
| D6  | 0.45        | 0.55 | 0.65 |
| D7  | 0.38 REF    |      |      |
| E   | 4.90        | 5.00 | 5.10 |
| E2  | 1.82        | 1.92 | 2.02 |
| E3  | 0.93        | 1.03 | 1.13 |
| E4  | 0.93        | 1.03 | 1.13 |
| E5  | 0.93        | 1.03 | 1.13 |
| E6  | 0.20        | 0.30 | 0.40 |
| E7  | 0.22 REF    |      |      |
| e   | 0.50 BSC    |      |      |
| e/2 | 0.25 BSC    |      |      |
| e/3 | 0.25 BSC    |      |      |
| e/4 | 0.75 BSC    |      |      |
| e/5 | 0.25 BSC    |      |      |
| k1  | 0.40 REF    |      |      |
| k2  | 0.45 REF    |      |      |
| k3  | 0.40 REF    |      |      |
| k4  | 0.30 REF    |      |      |
| k5  | 0.55 REF    |      |      |
| k6  | 0.50 REF    |      |      |
| k7  | 0.40 REF    |      |      |
| L   | 0.30        | 0.40 | 0.50 |
| L1  | 0.30        | 0.40 | 0.50 |
| L2  | 0.15        | 0.25 | 0.35 |
| m   | 0.15 REF    |      |      |
| n   | 0.80 REF    |      |      |
| p   | 2.28 REF    |      |      |
| q   | 2.38 REF    |      |      |
| r   | 0.80 REF    |      |      |
| z   | 0.625 REF   |      |      |

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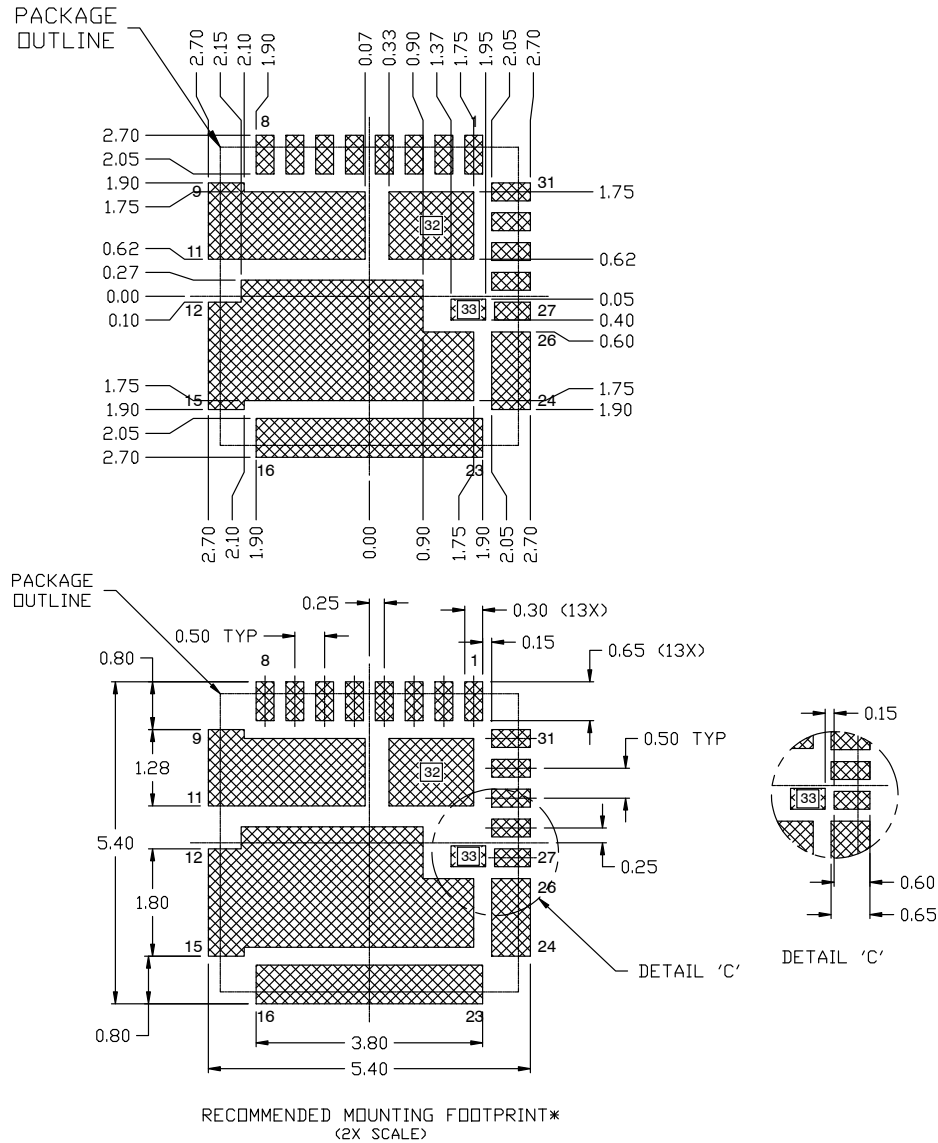
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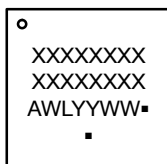
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**CASE 483BR**  
**ISSUE D**

DATE 13 FEB 2023



\* For additional information on our Pb-Free strategy and soldering details, please download the ONSEMI Soldering and Mounting Techniques Reference Manual, SOLDERM/D.

**GENERIC  
 MARKING DIAGRAM\***



XXXX = Specific Device Code  
 A = Assembly Location  
 WL = Wafer Lot  
 YY = Year  
 WW = Work Week  
 ■ = Pb-Free Package

(Note: Microdot may be in either location)

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

|                         |                         |                                                                                                                                                                                  |
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